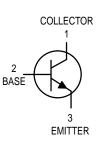
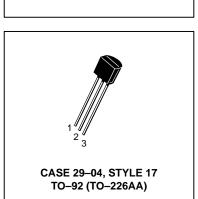
Amplifier Transistors

NPN Silicon





IOTOROLA

BC546, B

BC547, A, B, C BC548, A, B, C

MAXIMUM RATINGS

Rating	Symbol	BC 546	BC 547	BC 548	Unit
Collector-Emitter Voltage	VCEO	65	45	30	Vdc
Collector-Base Voltage	VCBO	80	50	30	Vdc
Emitter-Base Voltage	VEBO	6.0			Vdc
Collector Current — Continuous	IC	100			mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0		mW mW/°C	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12		Watt mW/°C	
Operating and Storage Junction Temperature Range	Т _Ј , Т _{stg}	-55 to +150			°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage $(I_C = 1.0 \text{ mA}, I_B = 0)$	BC546 BC547 BC548	V(BR)CEO	65 45 30	 		V
Collector-Base Breakdown Voltage ($I_C = 100 \ \mu Adc$)	BC546 BC547 BC548	V _(BR) CBO	80 50 30			V
Emitter-Base Breakdown Voltage (IE = 10 μ A, IC = 0)	BC546 BC547 BC548	V(BR)EBO	6.0 6.0 6.0			V
Collector Cutoff Current $(V_{CE} = 70 \text{ V}, V_{BE} = 0)$ $(V_{CE} = 50 \text{ V}, V_{BE} = 0)$ $(V_{CE} = 35 \text{ V}, V_{BE} = 0)$ $(V_{CE} = 30 \text{ V}, T_A = 125^{\circ}\text{C})$	BC546 BC547 BC548 BC546/547/548	ICES	 	0.2 0.2 0.2 —	15 15 15 4.0	nA μA

REV 1

BC546, B BC547, A, B, C BC548, A, B, C

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS						•
DC Current Gain (I _C = 10 μ A, V _{CE} = 5.0 V)	BC547A/548A BC546B/547B/548B BC548C	hFE		90 150 270		_
$(I_{C} = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC546 BC547 BC548 BC547A/548A BC546B/547B/548B BC546C/BC548C		110 110 110 110 200 420	 180 290 520	450 800 800 220 450 800	
$(I_{C} = 100 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC547A/548A BC546B/547B/548B BC548C		 	120 180 300	 	
Collector-Emitter Saturation Voltage ($I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA}$) ($I_C = 10 \text{ mA}, I_B = \text{See Note 1}$)		VCE(sat)		0.09 0.2 0.3	0.25 0.6 0.6	V
Base – Emitter Saturation Voltage $(I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA})$		V _{BE(sat)}	_	0.7	_	V
Base–Emitter On Voltage ($I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$) ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$)		VBE(on)	0.55 —		0.7 0.77	V
SMALL-SIGNAL CHARACTERISTICS		•				•
Current–Gain — Bandwidth Product (I _C = 10 mA, V _{CE} = 5.0 V, f = 100 MHz)	BC546 BC547 BC548	fΤ	150 150 150	300 300 300		MHz
Output Capacitance (V_{CB} = 10 V, I_{C} = 0, f = 1.0 MHz)		C _{obo}	_	1.7	4.5	pF
Input Capacitance (V _{EB} = 0.5 V, I _C = 0, f = 1.0 MHz)		C _{ibo}	_	10	—	pF
Small–Signal Current Gain (I _C = 2.0 mA, V _{CE} = 5.0 V, f = 1.0 kHz)	BC546 BC547/548 BC547A/548A BC546B/547B/548B BC547C/548C	h _{fe}	125 125 125 240 450	 220 330 600	500 900 260 500 900	-
Noise Figure (I _C = 0.2 mA, V _{CE} = 5.0 V, R _S = 2 k Ω , f = 1.0 kHz, Δ f = 200 Hz)	BC546 BC547 BC548	NF		2.0 2.0 2.0	10 10 10	dB

Note 1: I_B is value for which I_C = 11 mA at V_{CE} = 1.0 V.



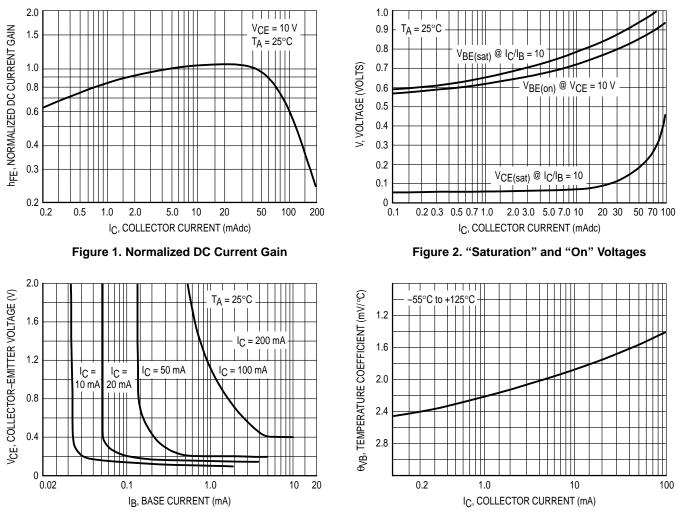
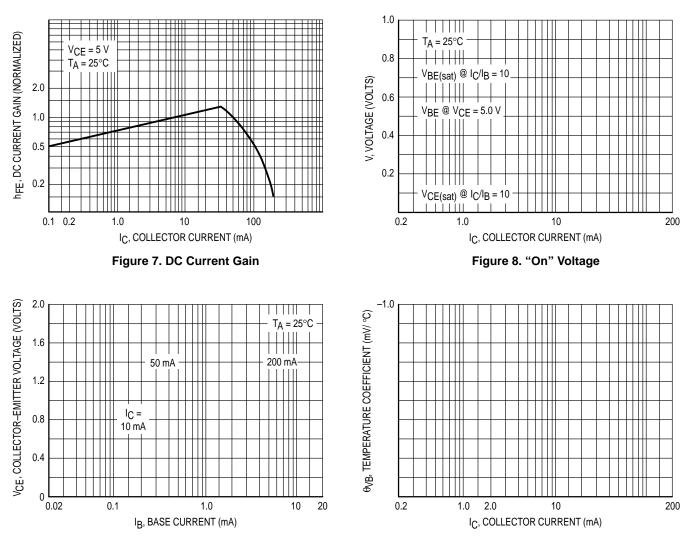


Figure 3. Collector Saturation Region

Figure 4. Base–Emitter Temperature Coefficient

BC546, B BC547, A, B, C BC548, A, B, C

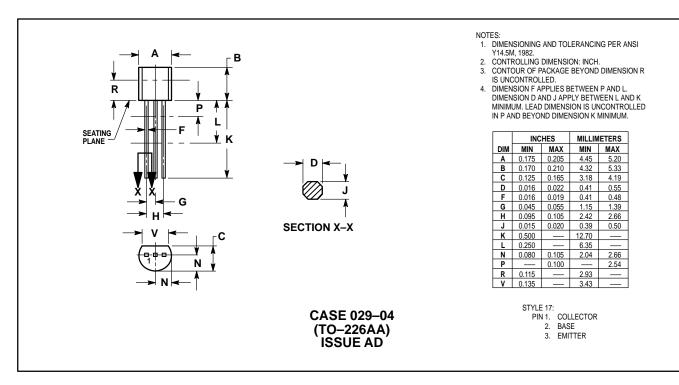


BC547/BC548

Figure 9. Collector Saturation Region

Figure 10. Base–Emitter Temperature Coefficient

PACKAGE DIMENSIONS



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